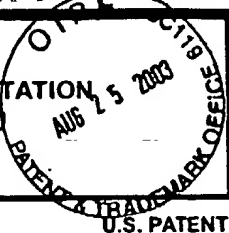


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<b>INFORMATION DISCLOSURE CITATION</b> (Use several sheets if necessary)	ATTY DOCKET NO. 03226.065001;P5347	SERIAL NO. 09/819,198
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## U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

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## FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

<i>KW</i>	B1	"Parasitic Resistance in an MOS Transistor Used as On-Chip Decoupling Capacitance" as published in IEEE JOURNAL OF SOLID-STATE CIRCUITS, Vol. 32, No. 4, April 1997 Author: Patrik Larsson (pages 574-576)
<i>KW</i>	B2	"Power Supply Noise in Future IC's: A Crystal Ball Reading" as published in IEEE 1999 CUSTOM INTEGRATED CIRCUITS CONFERENCE Author: P. Larsson (pages 467-474)

EXAMINER <i>KW</i>	DATE CONSIDERED 6/23/04
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.